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ABBREVIATIONS AND SYMBOLS

Physical constants

e_o = 1.602×10^{-19} C = elementary charge

h = 6.626×10^{-34} Js] = Planck constant

k_B = 1.381×10^{-23} J K^{-1} = Boltzmann constant

N_A = 6.022×10^{23} mol^{-1} = Avogadro's number

Physical variables

^{o}C	=	Degree Celcius
Å	=	Angstrom
f	=	Frequency
z	=	Collision frequency
λ	=	Wavelength
FF	=	Fill factor
E_g	=	Band gap energy
E_f	=	Fermi level
J_{sc}	=	Short circuit current density
V_{oc}	=	Open circuit voltage
η	=	Energy conversion efficiency
P_{in}	=	Incident light power
V_{max}	=	Maximum photovoltage
P_{max}	=	Maximum power output

R_{sh}	=	Shunt resistance
R_s	=	Series resistance
J_{lim}	=	Limited current density
$D_{I_3^-}$	=	Diffusion coefficient of I_3^-
$c_{I_3^-}$	=	Concentration of I_3^-
U	=	Energy transferred to a particle
Q	=	Electric charge
m	=	Mass of the particle
α	=	Total absorption coefficient
b	=	Path length
t	=	Effective thickness
ρ	=	Density of sample
T	=	Transmittance of photon
l	=	Distance between electrodes

Abbreviations

EDS	=	Energy Dispersive X-ray Spectroscopy
PL	=	Photoluminescence Spectrometry
SEM	=	Scanning Electron Microscopy
TEM	=	Transmission Electron Microscopy
XRD	=	X-Ray Diffraction Spectrometer
JCPDS	=	Joint Committee for Powder Diffraction Standards

IPCE	=	Incident photon-to-current conversion efficiency
HOMO	=	Highest occupied molecular orbital
LUMO	=	Lowest unoccupied molecular orbital
AM	=	Air mass
LHE	=	Light harvesting efficiency
DSSC	=	Dye-sensitized solar cell